



UNIVERSITY OF ENERGY AND NATURAL RESOURCES, SUNYANI, GHANA

SCHOOL OF ENGINEERING

DEPARTMENT OF COMPUTER AND ELECTRICAL ENGINEERING

Level 300: First Semester Examinations 2018/2019

Bachelor of Science (Computer Engineering, Electrical & Electronic Engineering)

ELNG 303: LINEAR ELECTRONIC CIRCUITS

DECEMBER, 2018

TIME: 2½ hours

**INSTRUCTIONS:** ANSWER ALL FIVE QUESTIONS: LECTURE MATERIALS CAN BE USED

Question 1 [(2x4)+(2+6)=16]

- (a) Briefly explain the following terms as applied to IC fabrication
- (i) Epitaxial Growth
  - (ii) Oxidation
  - (iii) Photolithography
  - (iv) Thin film deposition
- (b) A circuit is built around a bi-polar NPN transistor. The base network has a diode and a capacitor in series while the collector is connected to a power supply through a resistor. If the emitter is connected to ground:
- i) Draw the circuit
  - ii) Provide all the masking layout of the circuit

Question 2 [(4+(4x2)+(2x2)=14]

- (a) Given the circuit of Fig. 2.1, draw the small signal equivalent circuit assuming that  $r_D = \infty \Omega$  and show that:

$$V_{o1} = -\frac{g_m R_D}{1+g_m R_S} \quad \text{and} \quad V_{o2} = -\frac{g_m R_S}{1+g_m R_S}$$

For  $g_m=2\text{mS}$ ,  $R_G=1\text{M}\Omega$ ,  $R_S=R_D=5\text{k}\Omega$ , find  $V_{o1}$  and  $V_{o2}$  if  $V_i=20\text{mV Sin}\omega t$ .

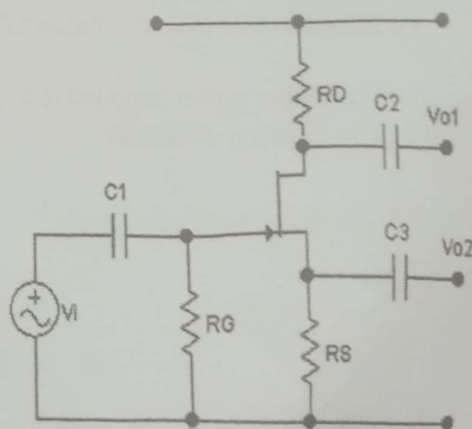


Fig. 2.1

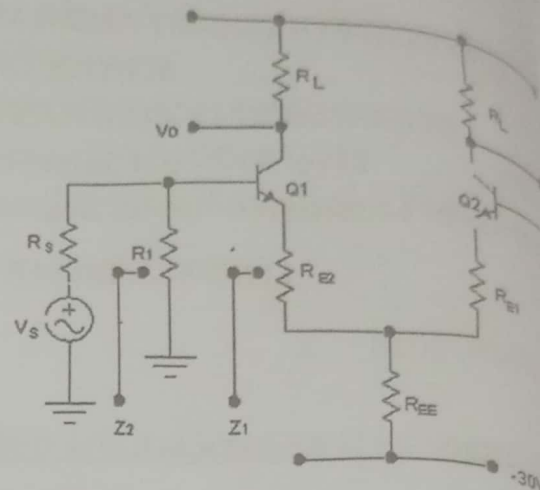
Question 3 [4+(2x5)=14]

(a) State four characteristics of an ideal op-amp.

(b) For the differential circuit shown in Fig. 3.1, given that  $\beta=100$ ,  $R_{E1}=R_{E2}=250\Omega$ ,  $R_{EE}=10k\Omega$ ,  $R_1=50k\Omega$ ,  $R_s=10k\Omega$ ,  $R_L=10k\Omega$  and  $V_s=10mV$ , determine:

- The current  $I_E$  through  $R_{EE}$
- The value of  $r_e$ , the emitter resistance
- The impedance  $Z_1$  looking through the base
- The impedance  $Z_2$
- The output voltage  $V_o$

Fig. 3.1

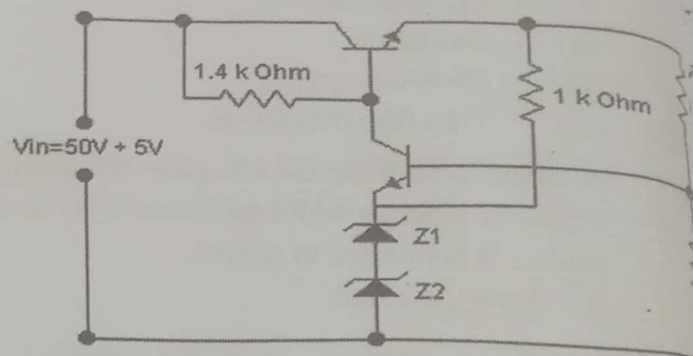


Question 4 [4+4=8]

(a) Distinguish between series and switching voltage regulators

(b) For the series voltage regulator shown in Fig. 4.1, determine the output regulated voltage if  $V_{Z1} = V_{Z2} = 7.5V$ ,  $V_{BE} = 0.7V$ ,  $R_1 = 930\Omega$  and  $R_2 = 1570\Omega$ .

Fig. 4.1



Question 5 [4+(2x2)=8]

(a) State the differences between the various types of power amplifier

(b) A complementary pair class B push-pull amplifier has a supply voltage of 45 V and the transistors are biased so that they are sinusoidally driven to provide a current 1.2A. Calculate:

- The output power supplied to a speaker having a resistance of  $15\Omega$
- The collector efficiency

UNIVERSITY OF E  
DEPARTMENT  
LEVEL 100: E  
DE

ember, 2018

struction (s):  
ver Question

- What is a
- State two stated.
- What is and op.
- Briefly
- Why
- State
- Sketch refer

(h) De

- i
- i

(j)



UNIVERSITY OF ENERGY AND NATURAL RESOURCES, SUNYANI, GHANA  
SCHOOL OF ENGINEERING

*DEPARTMENT OF COMPUTER AND ELECTRICAL ENGINEERING*

Level 300: First Semester Examinations 2020/2021

Bachelor of Science (Computer Engineering, Electrical & Electronic Engineering)

ELNG 303: LINEAR ELECTRONIC CIRCUITS

April, 2021

Time: 2½ hours

Material required: Class material (To be brought in by students)

**INSTRUCTIONS: ANSWER ALL QUESTIONS (each question carries 15marks)**

**Question 1**

(a) The following processes are used in the fabrication of monolithic ICs, explain each of them in detail:

- i. Oxidation
- ii. Diffusion
- iii. Epitaxy
- iv. Photolithography
- v. Thin Film Deposition

(b) Using the list in (a) provide a step-by-step masking levels of the fabrication of NPN transistor indicating the type of photo-resist used.

**Question 2**

The two-stage amplifier shown in Fig. 2 is designed with a *FET*, TR1 and silicon *BJT*, Q1 with the manufacturer's specifications for  $\beta$  (Q1) at 25°C as 150 and  $g_m$  (TR1) as 3500  $\mu S$ . Given  $R_g = 1.5k\Omega$ ,  $R_1 = 6M\Omega$ ,  $R_2 = 4M\Omega$ ,  $R_d = 2.4k\Omega$ ,  $R_s = 500\Omega$ ,  $R_3 = 15k\Omega$ ,  $R_4 = 4.7k\Omega$ ,  $R_c = 2.7k\Omega$ ,  $R_e = 470\Omega$ ,  $R_L = 2.2k\Omega$  and supply voltage as 20V. Using the Fig. 2 and component values given, answer the following questions.

Calculate:

- i) Emitter current  $I_e$
- ii) Emitter resistance  $r_e$
- iii) Voltage gain at stage 2,  $A_{v2}$
- iv) Calculate input impedance of the second stage,  $Z_2$
- v) Calculate the gain of the first stage,  $A_{v1}$
- vi) Calculate the input impedance of the first stage  $Z_1$
- vii) Calculate the overall gain,  $A$
- viii) If  $v_g$  is a sinusoidal voltage of 5mVcos $\omega t$ , what will the output voltage be?

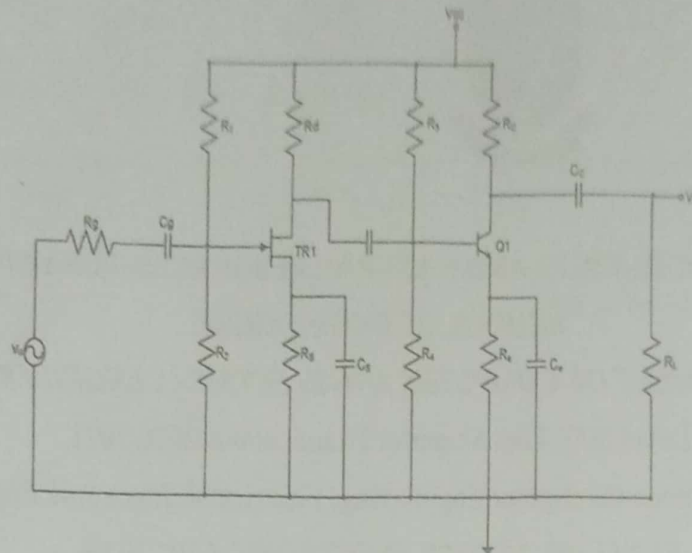


Fig. 2

### Question 3

- State and explain the different types of power amplifiers
- A complementary pair class B push-pull amplifier has a supply voltage of 45 V and the transistors are biased so that they are sinusoidally driven to provide a current which is 0.75 of the maximum value. Calculate:
  - The output power supplied to a speaker having a resistance of 15  $\Omega$
  - The collector efficiency
  - The power dissipation of the transistors.

### Question 4

- State the characteristics of an ideal op-amp.
- Fig. 4 shows the schematic of the two op-amp instrumentation amplifier. Find
  - An expression for  $V_{O1}$  and  $V_{O2}$
  - Hence or otherwise an expression if  $R_1 = R_2 = R_3 = R$
  - The current through  $R_L$  if  $R_L = 10\text{K}\Omega$  and  $V_i = 5\text{V}$

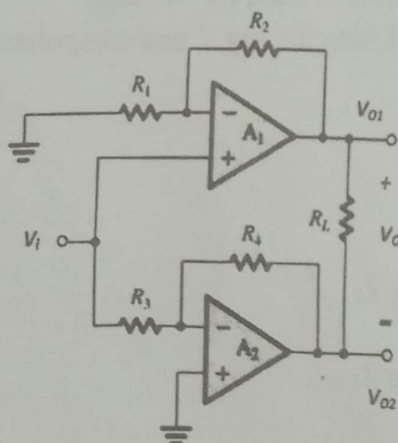


Fig. 4